# 1 Characteristics

Symbol	Pa	Value	Unit	
V <sub>PP</sub>	Peak pulse voltage	IEC 61000-4-2 air discharge IEC 61000-4-2 contact discharge MIL STD883G-Method 3015-7	±15 ±15 ±25	kV
T <sub>stg</sub>	Storage temperature range		-55 to +150	°C
Тj	Maximum junction temperature+125		+125	°C
ΤL	Lead solder temperature (10 seconds duration)		260	°C

Table	1.	Absolute	ratings
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Sympol	Deveneter	Toot conditions	Value			Unit
Symbol	Parameter	lest conditions	Min.	Тур.	Max.	Unit
I <sub>RM</sub>	Leakage current	$V_{RM} = 5 V$			0.5	μA
V <sub>BR</sub>	Breakdown voltage between V <sub>BUS</sub> and GND	I <sub>R</sub> = 1 mA	6			V
Ve		I <sub>PP</sub> = 1 A, 8/20 μs Any I/O pin to GND			12	V
VCL		I <sub>PP</sub> = 5 A, 8/20 μs Any I/O pin to GND			17	V
C	Capacitance between I/O and	V <sub>R</sub> = 0 V, F = 1 MHz Any I/O pin to ground		1.0	1.2	
℃i/o-GND	GND	$V_R = 0 V, F = 240 MHz$ Any I/O pin to ground		0.7	0.85	۶E
$\Delta C_{i/o-GND}$	Capacitance variation between I/O and GND	V <sub>R</sub> = 0 V, F = 1 MHz Any I/O pin to ground		0.02		μr
<u>Curran</u>		V <sub>R</sub> = 0 V, F = 1 MHz Ground not connected		0.47	0.55	
Ƴi/o-i/o	Capacitance between 1/O	V <sub>R</sub> = 0 V, F = 240 MHz Ground not connected		0.45	0.55	

### Table 2. Electrical characteristics (T<sub>amb</sub> = 25 °C)



3GHz

Figure 2. Relative variation of leakage current versus junction temperature (typical values)







Figure 6. Remaining voltage on I/O1 after USBULC-2P6 during positive ESD surge (+15 kV air discharge)



F(Hz)

10.0M 30.0M 100.0M 300.0M 1.0G 3.0G

Figure 3. Typical frequency response

<sub>0.00</sub> S21(db)

-4.00

-8.00

-12.00



Figure 7. Remaining voltage on I/O2 after USBULC-2P6 during negative ESD surge (-15 kV air discharge)





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100 ns/div

1000 D

Add no. 100 no

Figure 8. Remaining voltage on V<sub>BUS</sub> after USBULC-2P6 during positive ESD surge (+15 kV air discharge)





Figure 10. Eye diagram PCB only, 400 mV amplitude, F = 480 Mbps







Figure 12. Eye diagram PCB + USBULC6-2P6, +5 V on  $V_{BUS}$ , decoupling capacitor 100 nF, 400 mV amplitude, F = 480 Mbps

10 V/div

-20.61





## 2 Ordering information scheme

Product designation	
Ultra low capacitance	
Breakdown voltage 6 = 6 Volts	
Number of lines protected 2 = 2 lines	
Package P6 = SOT-666	



### 3 Package information

• Epoxy meets UL94, V0

In order to meet environmental requirements, ST offers these devices in ECOPACK<sup>®</sup> packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at *www.st.com*.



Table 3. SOT-666 dimensions

### Figure 14. SOT-666 footprint



Figure 15. SOT-666 marking



## 4 Ordering information

Table	4	Ordering	information
Table	<b>- -</b> -	Ordening	mormation

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
USBULC6-2P6	R	SOT-666	2.9 mg	3000	Tape and reel

### 5 Revision history

Date	Revision	Description of changes
31-Mar-2014	1	First issue.



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